Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

- 2. (Currently Amended) The composition according to Claim 1, wherein the solvent containing a glycol medium.
- 3. (Currently Amended) The composition according to Claim 2, wherein the content of the glycol medium in the solvent ranges from 40 to 55 percent by weight.
- 4. (Currently Amended) The composition according to Claim 2, wherein the glycol medium includes including diethylene glycol and a mixture containing the same.
- 5. (Currently Amended) The composition according to Claim 2, wherein the glycol medium includes including monoethylene glycol and a mixture containing the same.
- 6. (Currently Amended) The composition according to Claim 2, wherein the glycol medium includes-including triethylene glycol and a mixture containing the same.
- 7. (Currently Amended) The composition according to Claim 1, wherein the organic conductive material includes including polythiophene derivatives.
- 8. (Currently Amended) The composition according to Claim 1, wherein the organic conductive material includes including a mixture of polydioxythiophene and polystyrene sulfonic acid.
- 9. (Currently Amended) The composition according to Claim 1, wherein the organic conductive material includes including a mixture of polyaniline and polystyrene sulfonic acid.

- 10. (Currently Amended) The composition according to Claim 2, wherein the solvent containing an acetylenic glycol alcohol surfactant.
- 11. (Currently Amended) The composition according to Claim 10, wherein the content of the acetylenic glycol-alcohol surfactant in the solvent ranges ranging from 0.01 to 0.1 percent by weight.
- 12. (Currently Amended) The composition according to Claim 10, wherein the acetylenic glycol alcohol surfactant has having a boiling point that is less than or equal to that of the medium as well as the surfactant contained in the solvent.
- 13. (Currently Amended) The composition according to Claim 10, wherein the acetylenic glycol-alcohol surfactant includes 3,5-dimethyl-1-octyne-3-ol.
- 14. (Currently Amended) The composition according to Claim 1, wherein the composition is being subjected to degassing treatment.
- 15. (Currently Amended) The composition according to Claim 14, wherein the degassing treatment is being performed at a vacuum pressure that is less than or equal to the saturation vapor pressure of water.
- 16. (Currently Amended) The composition according to Claim 14, wherein before the degassing treatment, the composition contains containing an amount of the medium vaporized in the degassing treatment in advance.
- 17. (Currently Amended) An organic semiconductive layer comprising layer,

 comprising:

 a composition according to any one of Claims 1 to 16. Claim 1.

 18. (Currently Amended) A method for manufacturing to manufacture organic conductive layers, comprising comprising:

____an application step of applying a composition to different portions by an inkjet process, the composition being set forth in any one of Claims 1 to 16. Claim 1.

19.	(Currently Amended) The organic conductive layer-manufacturing method	
according to Claim 18. Claim 18, further comprising a drying step of comprising:		
1	removing a solvent after the application step.	
20.	(Currently Amended) The organic conductive layer-manufacturing method	
according to Claim 19, wherein the drying step is removing being performed in a vacuum		
atmosphere.		
21.	(Currently Amended) The organic conductive layer-manufacturing method	
according to Claim 20, wherein the drying step is removing being performed at a pressure of		
1.333×10^{-3} Pa or less and a temperature substantially equal to room temperature.		
22.	(Currently Amended) The organic conductive layer-manufacturing method	
according to Claim 19-Claim 19, further comprising a heating step of comprising:		
	performing thermal treatment at 100°C or more after the drying step.removing	
23.	(Currently Amended) The organic conductive layer-manufacturing method	
according to Claim 22, wherein a heat source used in the heating step includes thermal		
treatment including infrared rays.		
24.	(Currently Amended) An organic EL element comprising element,	
comprising:		
	a hole injection/transport layer eomprising including the organic conductive	
layer according to Claim 17.		
25. ((Currently Amended) A method for manufacturing to manufacture organic EL	
elements, comprising a step of comprising: forming hole injection/transport layers each		

26. (Currently Amended) An electronic device comprising device, comprising:

eomprising including the organic conductive layer according to Claim 17 by an inkjet

process.

	_at least the organic EL element according to Claim 24 and a circuit for driving	
to drive the organic EL element.		
27.	(Currently Amended) An electronic apparatus comprising apparatus,	
comprising:		
	_the electronic device according to Claim 26.	
28.	(Currently Amended) An organic semiconductor element comprising element,	
comprising:		
	_a source, a drain, a gate or wiring lines, which are conductive portions	
included in an integrated circuit, each comprising including the organic conductive layer		
according to Claim 17.		
29.	(Currently Amended) A method for manufacturing organic semiconductor	
elements, comprising a step of comprising:		
	_forming a drain, a gate or wiring lines, which are conductive portions included	
in an integrated circuit, by an inkjet process using the organic conductive layer according to		
Claim 17.		